HME/D-010

DECLARATION AND POWER OF ATTORNEY

As a below named inventor	, I hereby declare that:		
My residence, post office an	d citizenship are as stated below	v next to my name,	
names are listed below) of th SEMICONDUCTOR DE	e subject matter claimed and for VICE AND FABRICATING	which a patent is sought on the METHOD THEREOF, the s	
[X] is attached hereto	PY [] was filed on amended on	as Application Serial N	Ioand w as
I hereby state that I have a amended by any amendment		ontents of the above identified	specification, including the claims, as
I acknowledge the duty to o Code of Federal Regulation		own to me to be material to pa	tentability in accordance with Title 37,
certificate, or 365(a) of any America, listed below and	PCT international application have also identified below, by	which designated at least one concecting the box, any foreign	n application(s) for patent or inventor's ountry other than the United States of an application for patent or inventor's pplication on which priority is claimed.
Prior Foreign Application	n(s): <u>Country</u>		oreign Filing Date onth/Day/Year
28366/2000	Republic of Korea		25, 2000
I hereby claim the benefit Application Number(s):	under 35 U.S.C. 119(e) of any U <u>Fili</u>	inited States provisional applica	ation(s) listed below.
designating the United States is not disclosed in the prior U.S.C. 112, I acknowledge	ates of America, listed below and or United States or PCT internate the duty to disclose information the filing date of the prior applicates.	d, insofar as the subject matter tional application in the manne on which is material to patenta	c) of any PCT international application of each of the claims of this application or provided by the first paragraph of 35 ability as defined in 37 CFR 1.56 which ternational filing date of this application. Parent Patent Number (if

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that

such willful false statements may jeopardize the validity of the application or any patent issued thereon. I hereby appoint the following attorney(s) and/or agent(s):Daniel Y.J. Kim, Registration No. 36,186 and Mark L. Fleshner, Registration No. 34,596; Carl R. Wesolowski, Registration No. 40,372, John C. Eisenhart, Registration No. 38,128, Carol L. Druzbick, Registration No. 40,287; and Anthony H. Nourse, Registration No. 46,121, all of

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with full power of substitution and revocation, to prosecute this application and to transact all business in the Patent and Trademark Office connected therewith, and all future correspondence should be addressed to them.

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